Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L3	281	(photodiode or (photo adj diode)) same (trench or hole) and ((impurity or separation) adj region)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 14:48
L4	127	3 and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 15:27
L5	912	(photodiode or (photo adj diode)) same ((trench or hole) and (impurity or (separation adj region)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 15:27
L6	430	5 and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2007/05/10 15:28
L7	912	(photodiode or (photo adj diode)) same ((trench or hole) and (impurity or (separation adj region)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 15:28
L8	430	L7 and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 15:28
L9	0	6 not L8	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 15:28
L10	1434	(photodiode or (photo adj diode)) same (trench or hole) and (impurity or (separation adj region))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 15:37

L11	1	L10 and @ad<"2003"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT;	OR	ON	2007/05/10 15:32
L12	759	L10 and @ad<"20030101"	IBM_TDB US-PGPUB; USPAT; USOCR;	OR	ON	2007/05/10 15:38
			EPO; JPO; DERWENT; IBM_TDB			
L13	1004	L10 not 8	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 15:34
L14	1004	L10 not I8	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 15:34
L15	1004	L10 not L8	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 15:35
L16	329	L12 not L8	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 15:35
L17	281	(photodiode or (photo adj diode)) same (trench or hole) and (impurity or separation) adj region	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 15:40
L18	127	L17 and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 15:43

L19	273	(photodiode or (photo adj diode)) same (trench or hole) same (polysilicon or metal) same (polish\$3 remov\$3 etch\$3 CMP)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2007/05/10 17:18
L20	143	L19 and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 17:17
L21	2	"2001318155"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 16:59
L22	171	(photodiode or (photo adj diode)) same (trench or hole) same (polysilicon or metal or conducti\$2) same (polish\$3 remov\$3 etch\$3 CMP) same (wir\$3 connect\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 17:17
L23	· 80	L22 and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 17:19
L24	66	((photodiode or (photo adj diode) (photodetector) (photo-detector)) and sensor) same (trench or hole) same (polysilicon or metal) same (polish\$3 remov\$3 etch\$3 CMP)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 17:27
L25	31	L24 and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 17:19
L26	5	((photodiode or (photo adj diode) (photodetector) (photo-detector)) and sensor) same ((trench or hole) with substrate) same (polysilicon or metal) same (polish\$3 remov\$3 etch\$3 CMP) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 17:36

				•		
L27	7	((photodiode or (photo adj diode) (photodetector) (photo-detector)) and sensor) same ((trench or hole aperture) with substrate) same (polysilicon or metal or conducti\$3) same (polish\$3 remov\$3 etch\$3 CMP) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 17:37
L29	361	(photodiode or (photo adj diode)) and array same (impurity or (separation adj region)) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 20:11
L30	204	((photodiode or (photo adj diode)) and array) same (impurity or (separation adj region)) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 20:14
L31	. 3	((photodiode or (photo adj diode)) and array) same (impurity with (separation adj region)) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 20:17
L32	3	((photodiode or (photo adj diode)) and array) same ((impurity dop\$3) with (separat\$3 adj region)) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 20:17
L33	11	((photodiode or (photo adj diode)) and array) same ((impurity dop\$3) with ((separat\$3 isolat\$3) adj region)) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 20:22
L34	8	((photodiode or (photo adj diode)) and array) with ((impurity dop\$3) with ((separat\$3 isolat\$3) adj region)) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 20:23
L35	0	((photodiode or (photo adj diode)) and array) same ((impurity dop\$3) same (((separat\$3 isolat\$3) adj region)) with electrical\$2) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 20:25

5/11/2007 12:53:26 AM C:\Documents and Settings\schhaya\My Documents\EAST\Workspaces\10541957.wsp

L36	0	((photodiode or (photo adj diode))	US-PGPUB;	OR	ON	2007/05/10 20:25
	0	and array) same ((impurity dop\$3) same (((separat\$3 isolat\$3) adj region)) with electrical) and @ad<"20030101"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB			2307, 03, 10 20.23
L37	4	((photodiode or (photo adj diode)) and array) same ((impurity dop\$3) and electrical\$2 same ((separat\$3 isolat\$3) adj region)) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 20:34
L38	13	((photodiode or (photo adj diode)) and array) same ((impurity dop\$3) and electrical\$2 with ((separat\$3 isolat\$3) with region)) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 20:34
L39	1	37 not 38	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 20:35
L40	10	38 not 37	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 21:26
L41	57	organic and transistor and (u adj shaped near channel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 21:30
L42	26	41 and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 21:28
L43	1	("5563077").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/05/10 21:28

Page 5

L44	58	organic and transistor and (((u adj shaped) or meandering) near channel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 21:37
L45	5	organic and transistor and (((u adj shaped) or meandering) near channel) and (NAND or NOR)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 21:32
L46	546	Fix.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 21:32
L47	74	Fix-Walter.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 21:33
L48	13	47 and (((u adj shaped).clm. and organic.clm.) OFET.clm.)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 21:33
L49	26	organic and transistor and (((u adj shaped) or meandering) adj channel) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 22:03
L50	36	organic and transistor and ((holes interruptions) with (semiconducting adj layer)) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 22:26
L51	0	organic and transistor and (((holes interruptions) with (semiconducting adj layer)) same leakage) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 22:26

L52	36	organic and transistor and (((holes interruptions) with (semiconducting adj layer))) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 22:28
L53	36	organic and transistor and (((pattern\$ interruptions) with (semiconducting adj layer))) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 22:30
L54	0	organic and transistor and (((interruption) with (semiconducting adj layer))) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 22:30
L55	28	organic and transistor and (((patterned) with (semiconducting adj layer))) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 22:31
L56	983	organic and transistor and (((patterned) with (semiconductor adj layer))) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 22:32
L57	288	organic and transistor and (((patterned) with (semiconductor adj layer)) and leakage) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 22:35
L58	3	organic and transistor and (((patterned) with (semiconductor adj layer)) with leakage) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 22:36
L59	2	organic and transistor and (((patterned) with (semiconductor adj layer)) with leak\$3 adj current) and @ad<"20030101"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 22:36

S1	435	OFET	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/30 14:39
S2	5195832	@ad>"20030114"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/30 14:40
S3	167	S1 not S2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/01 17:42
S4	1	("7064345").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/04/30 14:43
S5	3	(("6197663") or ("6326288") or ("6362509")).PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/04/30 14:57

S6	66	US-20020022284-\$.DID. OR	US-PGPUB;	OR	ON	2007/04/30 14:58
30	00	l '		OK	ON	200//04/30 14:36
	•	US-20020053320-\$.DID. OR	USPAT;			
		US-20020056839-\$.DID. OR	USOCR			
		US-20020068392-\$.DID. OR				
		US-20020170897-\$.DID. OR				
		US-20020018911-\$.DID. OR				
		US-20020195644-\$.DID. OR				
	İ	US-20030112576-\$.DID. OR				
		US-20040002176-\$.DID. OR				
		US-20040013982-\$.DID. OR				
		US-20040026689-\$.DID. OR				
		US-20040084670-\$.DID. OR				
		US-20040211329-\$.DID. OR				
		US-3512052-\$.DID. OR				
:		US-3769096-\$.DID. OR				
		US-3955098-\$.DID. OR				
		US-4302648-\$.DID. OR				
		US-4442019-\$.DID. OR				
		US-4926052-\$.DID. OR				
İ	į	US-4865197-\$.DID. OR				
		US-5173835-\$.DID. OR				
	1	US-5206525-\$.DID. OR				
		US-5259926-\$.DID. OR				
		US-5321240-\$.DID. OR				
		US-5347144-\$.DID. OR				
		US-5395504-\$.DID. OR				
		US-5480839-\$.DID. OR				
	,	US-5486851-\$.DID. OR				
	1	US-5502396-\$.DID. OR				
		US-5546889-\$.DID. OR				
		US-5569879-\$.DID. OR			:	
		US-5574291-\$.DID. OR		1		
İ		US-5578513-\$.DID. OR				
		US-5580794-\$.DID. OR				
		US-5629530-\$.DID. OR				
		US-5630986-\$.DID. OR				
		US-5652645-\$.DID. OR		•		
		US-5691089-\$.DID. OR				
		US-5854139-\$.DID. OR				
		US-5869972-\$.DID. OR			!	
		US-5892244-\$.DID. OR				
		US-5946551-\$.DID. OR				
		•			1	
		US-5967048-\$.DID. OR				
		US-5973598-\$.DID. OR				
		US-5997817-\$.DID. OR				
		US-6036919-\$.DID. OR				
		US-6045977-\$.DID. OR				
		US-6060338-\$.DID. OR				
		US-6083104-\$.DID. OR				
		US-6133835-\$.DID. OR				
		US-6207472-\$.DID. OR				
		US-6215130-\$.DID. OR				
		US-6251513-\$.DID. OR				
		US-6284562-\$.DID. OR				
F/11/200	07 12:53:26 A	MUS-6300141-\$.DID. OR				Dage O
C-/ Docin	ments and Set	LUST6322736-S. DID OR LEVENSTVALLE	naces\1054105	7 wen		Page 9
C. \0000	THE IS AND SEC	TUS-6332736-\$ DID OR tings-6335539-\$ DID OR US-6335539-\$ DID. OR	haces/1024122	η, .wsp		
1		110 4340033 # DID OD	l	I		

S7	14047	organic with transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/02 21:06
S8	5198781	@ad>"20030114"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/01 17:42
S9	4118	S7 not S8	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/01 17:42
S10	2323	(257/40).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/05/01 17:42
S11	244	S9 and S10	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/01 17:43
S12	14047	organic with transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/02 21:06
S13	154	S12 and interdigita\$6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/02 21:08
S14	5198781	@ad>"20030114"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/02 21:08

S15	79	S13 not S14	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/02 21:08
S16	1	("6197663").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/05/02 22:10
S17	1	("6362288").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/05/02 22:10
S18	1	("6326288").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/05/02 22:10
S19	16	(US-20010045593-\$ or US-20010048379-\$).did. or (US-6545291-\$ or US-6362509-\$ or US-6326288-\$ or US-6870182-\$ or US-5970318-\$ or US-6852555-\$ or US-5079595-\$ or US-6433357-\$ or US-6818920-\$ or US-3999122-\$ or US-5535231-\$ or US-6806815-\$ or US-6870186-\$ or US-6197663-\$).did.	US-PGPUB; USPAT	OR	ON	2007/05/09 20:43
S20	5	S19 and "interdigitated"	US-PGPUB; USPAT	OR	ON	2007/05/09 20:43
S21	1434	(photodiode or (photo adj diode)) same (trench or hole) and (impurity or (separation adj region))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 15:27
S23	912	(photodiode or (photo adj diode)) same ((trench or hole) and (impurity or (separation adj region)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 20:04
S24	1	S23 and @ad<"2003"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 13:47

S25	430	S23 and @ad<"20030101"	US-PGPUB;	OR	ON	2007/05/10 14:50
			USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB			
S26	0	"rose.kiesha.xa"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 13:59
S27	178	rose-kiesha.xa.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 14:04
S28	133817	S27 and photodiode or photodetector or (photo adj diode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 14:00
S29	11	S27 and (photodiode or photodetector or (photo adj diode))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 14:00
S30	9	rose-kusha.xa.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/10 14:04

Page 12 5/11/2007 12:53:26 AM C:\Documents and Settings\schhaya\My Documents\EAST\Workspaces\10541957.wsp